- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes
 PCB Layout
- Center-Pin V_{CC} and GND Pin Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages and Standard Plastic 300-mil DIPs

DW OR N PACKAGE (TOP VIEW) \overline{A}/B 20 T 1A 1Y 🛮 19 1 1B 2Y 🛮 3 18 1 2A 17 2B GND [] 4 GND ∏ 5 16 V_{CC}] v_{cc} GND [] 15 GND 17 14 3A 3Y 🛮 8 13 3B 12**∏** 4A 4Y OE 10 11 🛮 4B

description

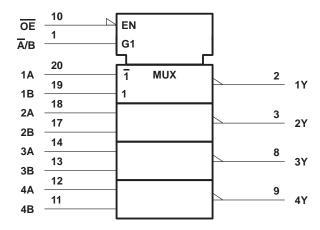
This data selector/multiplexer contains inverters and drivers to supply full data selection to the four output gates. A separate output-enable (\overline{OE}) input is provided. A 4-bit word is selected from one of two sources and is routed to the four outputs. The 74ACT11158 provides inverted data.

The 74ACT11158 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE

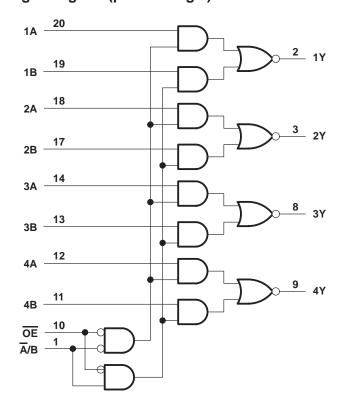
	INPU	OUTPUT				
OE	A/B	Α	В	Υ		
Н	Х	Χ	Х	Н		
L	L	L	X	Н		
L	L	Н	X	L		
L	Н	Χ	L	Н		
L	Н	Χ	Н	L		

logic symbol†



EPIC is a trademark of Texas Instruments Incorporated.

logic diagram (positive logic)



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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SCAS181 - D3979, JANUARY 1992 - REVISED APRIL 1993

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} –0.5 V t	o 7 V
Input voltage range, V _I (see Note 1) –0.5 V to V _{CC} +	0.5 V
Output voltage range, V _O (see Note 1)0.5 V to V _{CC} +	0.5 V
Input clamp current, $I_{ K }(V_1 < 0 \text{ or } V_1 > V_{CC})$ ± 2	0 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	0 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$ ± 5	0 mA
Continuous current through V _{CC} or GND ±10	0 mA
Storage temperature range –65°C to 1	50°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
٧ _I	Input voltage	0		VCC	V
VO	Output voltage	0		VCC	V
IOH	High-level output current			-24	mA
loL	Low-level output current			24	mA
Δt/Δν	Input transition rise or fall rate	0		10	ns/V
TA	Operating free-air temperature	-40		85	°C

NOTE 2: Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	v _{cc}	T _A = 25°C			MINI	MAY	UNIT
PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	UNII
Voн	I _{OH} = -50 μA	4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		V
	Jan. 24 mA	4.5 V	3.94			3.8		
	I _{OH} = −24 mA		4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\ddagger}$	5.5 V				3.85		
VOL	Ι _{ΟL} = 50 μΑ	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
	I _{OL} = 24 mA	4.5 V			0.36		0.44	V
		5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\ddagger}$	5.5 V					1.65	
IĮ	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1	μΑ
lcc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			8		80	μΑ
∆l _{CC} §	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			0.9		1	mA
Ci	$V_I = V_{CC}$ or GND	5 V		3.5				рF

[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

[§] This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.



NOTE 1: The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

SCAS181 - D3979, JANUARY 1992 - REVISED APRIL 1993

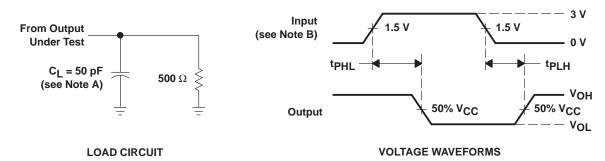
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX	IWIIIN	IVIAA	OINII
t _{PLH}	A or B	Y	2	5.1	7.6	2	8.4	ns
t _{PHL}			2.7	5.9	8.3	2.7	9.4	
^t PLH	A/B	V	2.3	5.3	7.7	2.3	8.5	ns
t _{PHL}		'	2.9	6.7	9.8	2.9	10.8	115
^t PLH	ŌĒ	V	2.5	5.1	6.8	2.5	7.5	20
tPHL		ľ	2.5	6.1	8.9	2.5	10	ns

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CON	TYP	UNIT	
C _{pd}	Power dissipation capacitance	$C_L = 50 pF$,	f = 1 MHz	37	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f = 3 \ ns$, $t_f = 3 \ ns$.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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